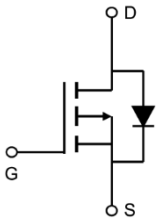
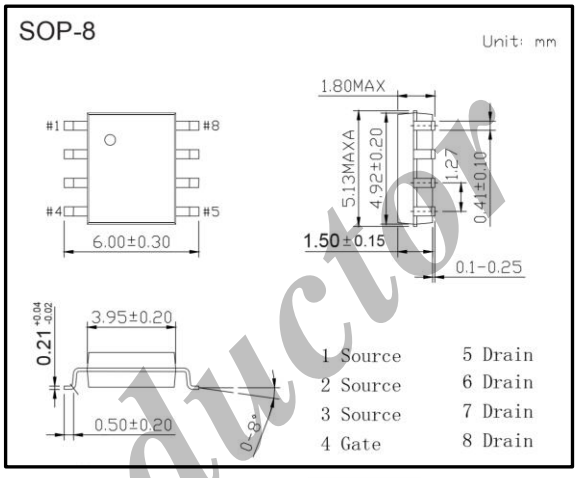
AP4403
30V P-Channel Enhancement Mode MOSFET

- **General Description**

AP4403 combines advanced MOSFET technology with a low resistance package to provide extremely low $R_{DS(ON)}$. This device is most suitable to load switch or PWM applications.

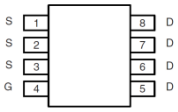




- **Applications**

- DC-DC converter for portable devices
- Load switch

Top View



- **Product Summary**

V_{DS}	-30V
I_D (at V_{GS} = -10V)	-6A
$R_{DS(ON)}$ (at V_{GS} = -10V)	< 48mΩ
$R_{DS(ON)}$ (at V_{GS} = -4.5V)	< 57mΩ
$R_{DS(ON)}$ (at V_{GS} = -2.5V)	< 80mΩ

- **Absolute Maximum Ratings Ta = 25°C**

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V_{DS}	-30	V
Gate-Source Voltage		V_{GS}	±12	V
Continuous Drain Current	Ta = 25°C	I_D	-6	A
	Ta = 70°C		-5	
Pulsed Drain Current		I_{DM}	-30	
Avalanche Current		I_{AS}, I_{AR}	18	
Avalanche Energy (L = 0.1mH)		E_{AS}, E_{AR}	16	mJ
Power Dissipation	Ta = 25°C	P_D	3.1	W
	Ta = 70°C		2	
Junction and Storage Temperature Range		T_J, T_{STG}	-55 to 150	°C
Thermal Characteristics				
Thermal Resistance. Junction-to-Ambient	t ≤ 10s	$R_{\theta JA}$	40	°C/W
	Steady State		75	
Thermal Resistance. Junction-to-Lead	Steady State	$R_{\theta JL}$	24	

- **Electrical Characteristics Ta = 25°C**

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Parameters						
Drain-Source Breakdown Voltage	V_{DSS}	I_D=-250μA, V_{GS}=0V	-30			V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=-30V, V_{GS}=0V			-1	μA
		V_{DS}=-30V, V_{GS}=0V, T_J=55°C			-5	
Gate-Body Leakage Current	I_{GSS}	V_{DS}=0V, V_{GS}=±12V			±100	nA
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS}, I_D=-250μA	-0.5	-0.9	-1.3	V
On-State Drain Current	$I_{D(ON)}$	V_{GS}=-4.5V, V_{DS}=-5V	-30			A
Static Drain-Source On-Resistance	$R_{DS(ON)}$	V_{GS}=-10V, I_D=-6A		40	48	mΩ
		V_{GS}=-10V, I_D=-6A, T_J=125°C		60	72	
		V_{GS}=-4.5V, I_D=-4A		45	57	
		V_{GS}=-2.5V, I_D=-2A		60	80	
Forward Transconductance	g_{FS}	V_{DS}=-5V, I_D=-6A		19		S
Diode Forward Voltage	V_{SD}	I_S=-1A, V_{GS}=0V		-0.7	-1	V
Maximum Body-Diode Continuous Current	I_S				-3.5	A
Dynamic Parameters						
Input Capacitance	C_{iss}	V_{GS}=0V, V_{DS}=-15V, f=1MHz		645	780	pF
Output Capacitance	C_{oss}			80		
Reverse Transfer Capacitance	C_{rss}			55		
Gate Resistance	R_g	V_{GS}=0V, V_{DS}=0V, f=1MHz	4	7.8	12	Ω
Switching Parameters						
Total Gate Charge (4.5V)	Q_g	V_{GS}=-4.5V, V_{DS}=-15V, I_D=-6A		7		nC
Gate Source Charge	Q_{gs}			1.5		
Gate Drain Charge	Q_{gd}			2.5		
Turn-On Delay Time	$t_{D(on)}$	V_{GS}=-10V, V_{DS}=-15V, R_L=2.5Ω, R_{GEN}=6Ω		6.5		ns
Turn-On Rise Time	t_r			3.5		
Turn-Off Delay Time	$t_{D(off)}$			41		
Turn-Off Fall Time	t_f			9		
Body Diode Reverse Recovery Time	t_{rr}	I_F=-6A, d_i/d_t=100A/μs		11		
Body Diode Reverse Recovery Charge	Q_{rr}	I_F=-6A, d_i/d_t=100A/μs		3.5		nC

- **Ordering Information**

Ordering Part Number	Package	MOQ
AP4403	SOP-8	2,500 pcs / reel

- **Typical Electrical and Thermal Characteristics**

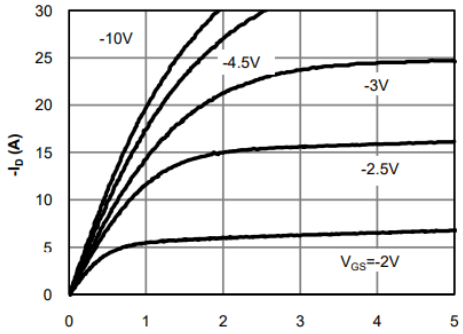


Fig 1: On-Region Characteristics

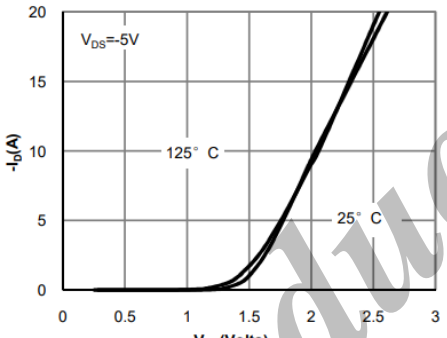


Figure 2: Transfer Characteristics

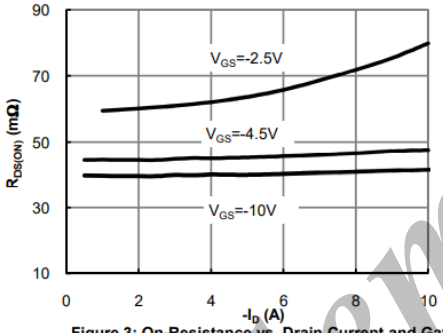


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

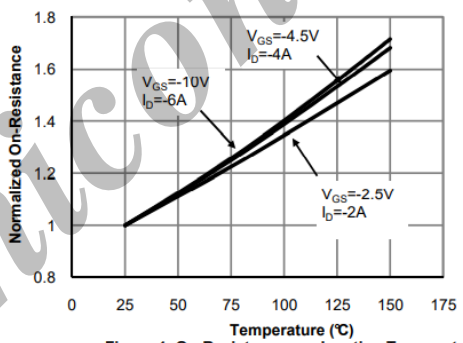


Figure 4: On-Resistance vs. Junction Temperature

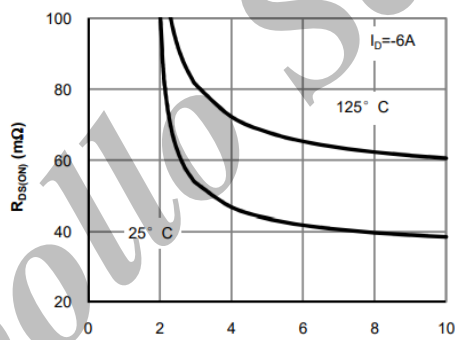


Figure 5: On-Resistance vs. Gate-Source Voltage

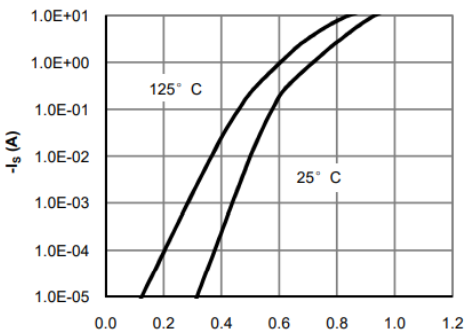


Figure 6: Body-Diode Characteristics

Note 1: The static characteristics in Figure 1 to 6 are obtained using <300μA pulses, duty cycle 0.5% max.

- **Typical Electrical and Thermal Characteristics**

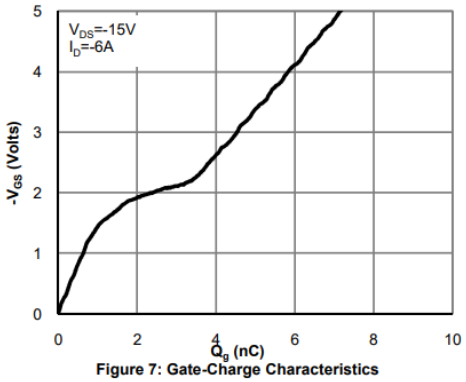


Figure 7: Gate-Charge Characteristics

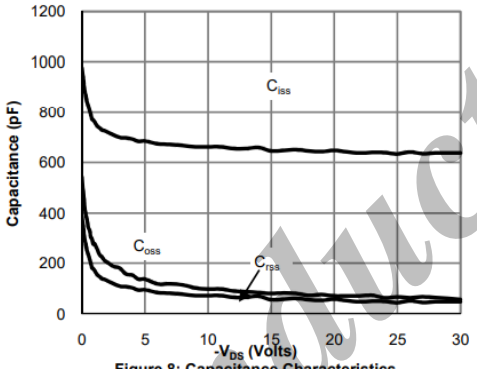


Figure 8: Capacitance Characteristics

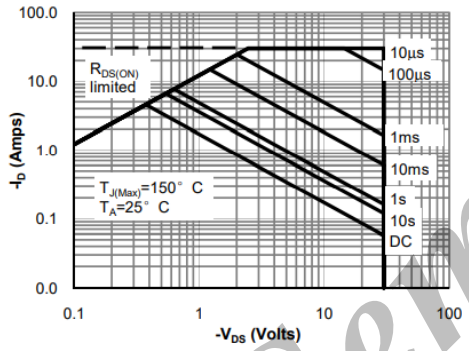


Figure 9: Maximum Forward Biased Safe Operating Area

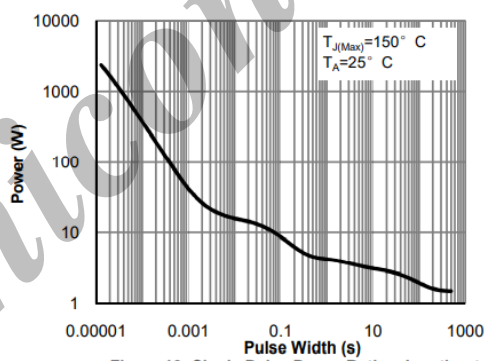


Figure 10: Single Pulse Power Rating Junction-to-Ambient

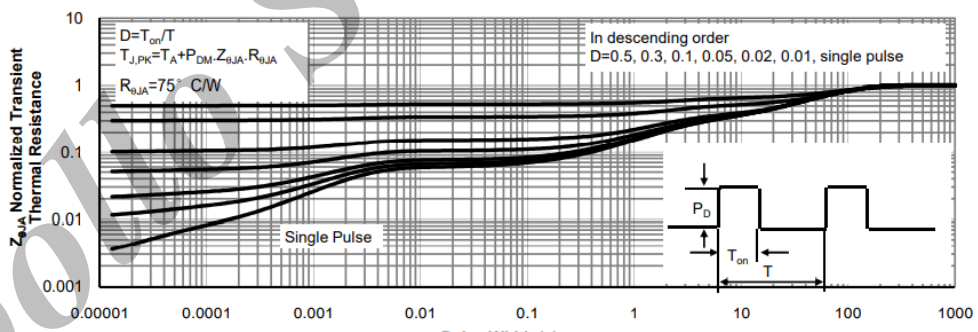


Figure 11: Normalized Maximum Transient Thermal Impedance

Note 2: The curves in Figure 10 to 12 are based on the junction-to-ambient thermal impedance which is measured with the device mounted on 1in² FR-4 board with 2oz. copper, assuming a maximum junction temperature of $T_{J(MAX)}$=150°C . The SOA curve provides a single pulse rating.

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